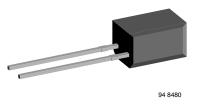
Vishay Semiconductors



Silicon PIN Photodiode, RoHS Compliant



BPW82 is a PIN photodiode with high speed and high radiant

sensitivity in a black, side view plastic package with daylight

blocking filter. Filter bandwidth is matched with 870 nm to

FEATURES

- Package type: leaded
- Package form: side view
- Dimensions (L x W x H in mm): 5 x 4 x 6.8
- Radiant sensitive area (in mm²): 7.5
- High radiant sensitivity
- Daylight blocking filter matched with 870 nm to 950 nm emitters
- · Fast response times
- Angle of half sensitivity: $\phi = \pm 65^{\circ}$
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

- High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSFFxxxx series IR emitters

PRODUCT SUMMARY						
COMPONENT	I _{ra} (μΑ)	φ (deg)	λ _{0.5} (nm)			
BPW82	45	± 65	790 to 1050			

Note

DESCRIPTION

950 nm IR emitters.

Test condition see table "Basic Characteristics"

ORDERING INFORMATION ORDERING CODE PACKAGING REMARKS PACKAGE FORM BPW82 Bulk MOQ: 4000 pcs, 4000 pcs/bulk Side view

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage		V _R	60	V			
Power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	Pv	215	mW			
Junction temperature		Тj	100	°C			
Operating temperature range		T _{amb}	- 40 to + 100	°C			
Storage temperature range		T _{stg}	- 40 to + 100	°C			
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C			
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA}	350	K/W			

Note

T_{amb} = 25 °C, unless otherwise specified



COMPLIANT



Silicon PIN Photodiode, RoHS Compliant

Vishay Semiconductors

BASIC CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	60			V	
Reverse dark current	V _R = 10 V, E = 0	I _{ro}		2	30	nA	
Diode capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	CD		70		pF	
	V _R = 3 V, f = 1 MHz, E = 0	CD		25	40	pF	
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 870 \text{ nm}$	Vo		350		mV	
Short circuit current	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 870 \text{ nm}$	l _k		38		μΑ	
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 870 \text{ nm},$ $V_R = 5 \text{ V}$	I _{ra}	43	45		μA	
Angle of half sensitivity		φ		± 65		deg	
Wavelength of peak sensitivity		λ _p		950		nm	
Range of spectral bandwidth		λ _{0.5}		790 to 1050		nm	
Noise equivalent power	$V_{R} = 10 V, \lambda = 870 nm$	NEP		4 x 10 ⁻¹⁴		W/√Hz	
Rise time	$V_R = 10 \text{ V}, \text{ R}_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _r		100		ns	
Fall time	$V_{R} = 10 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _f		100		ns	

Note

Tamb = 25 °C, unless otherwise specified

BASIC CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified

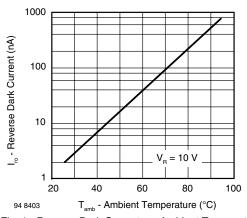


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

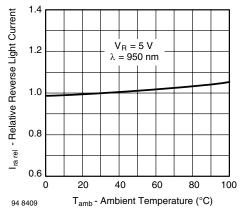


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

Vishay Semiconductors

Silicon PIN Photodiode, RoHS Compliant



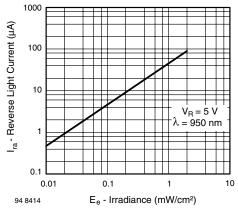


Fig. 3 - Reverse Light Current vs. Irradiance

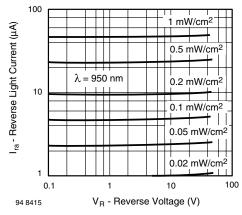


Fig. 4 - Reverse Light Current vs. Reverse Voltage

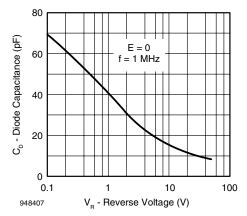


Fig. 5 - Diode Capacitance vs. Reverse Voltage

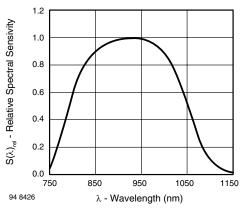


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

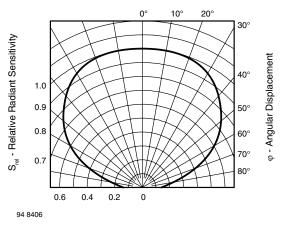


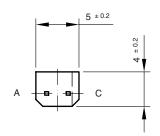
Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

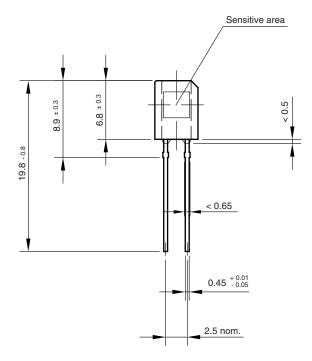


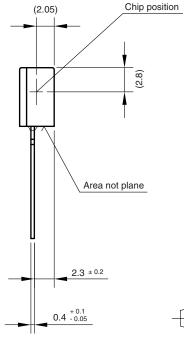
Vishay Semiconductors

BPW82

PACKAGE DIMENSIONS in millimeters









technical drawings according to DIN specifications

Drawing-No.: 6.544-5108.01-4 Issue:1; 01.07.96 96 12195



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.



单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)

>>点击查看相关商品